

RCC 反激式电路设计表

RCC Design_Rev1.02 Copyright Wuming Electric Inc. 2003		输入	信息	输出	单位	RCC Design_Rev1.02.xls: RCC Flyback Transformer Design Spreadsheet
ENTER APPLICATION VARIABLES						Customer
VACMIN	200				Volts	Minimum AC Input Voltage
VACMAX	240				Volts	Maximum AC Input Voltage
FI	50				Hz	Minimum AC input Frequency
Fmin	70				KHz	Minimum OSC Frequency
VO	7				Volts	Output Voltage
IO	0.5				Amps	Output Current
eta	0.7					Efficiency Estimate
Z	1					Loss Allocation Factor
tC	3				mSec	Bridge Rectifier Conduction Time Estimate
CIN	6.8				uFarads	Input Filter Capacitor
D	0.2					
T				14.2857143	uS	Max Time of Cycle
Ton				2.85714286	uS	On time of Cycle
Toff				11.4285714	uS	Off time of Cycle
d	2				A/mm²	副边线圈电流密度
ENTER Output Diode Parameters						
Output Diode	1N5822					
VR	60				Volts	Diode Maximum Peak Repetitive Reverse Voltage
ID	3				Amps	Diode Average Forward Current
VD	0.52				Volts	Diode Forward Voltage drop
Vo_1	12				Volts	Auxiliary Output Voltage
VD_1	0.6				Volts	Auxiliary Diode Forward Voltage Drop
Io_1					Amps	Auxiliary Output Current
Vo_2	5				Volts	second Output Voltage
VD_2	0.6				Volts	second Diode Forward Voltage Drop
Io_2					Amps	second Output Current
Vo_3	5				Volts	third Output Voltage
VD_3	0.6				Volts	third Diode Forward Voltage Drop
Io_3					Amps	third Output Current
PO				3.5		Output Power
P				6.02		Total Power
VB	21.5				Volts	Driver Output Voltage
VD_B	1					
IB	0.02				A	Driver Output Current
IB_min	0.0115				A	
ENTER Other Parameters						
BP	2300				Gauss	Target Peak Flux Density at Maximum Current limit
Direct Switch Type	MJE13001					
Bvceo	500				Volts	
Imax	0.5				Amps	
Hfe	20					
Design Parameters						
VMIN				264	Volts	Minimum DC Input Voltage
VMAX				339	Volts	Maximum DC Input Voltage
IP				0.23	Amps	Peak Primary current
N12				0.11		
LP				3280	uHenries	Minimum Primary Inductance
LS				42.97	uHenries	
RS				3	OM	
ENTER TRANSFORMER CORE/CONSTRUCTION						
Core Type	ee16		EE16			
AE			0.192		cm²	Core Effective Cross Sectional Area
LE			3.5		cm	Core Effective Path Length
AL			1140		nH/T²	Ungapped Core Effective Inductance
BW			8.5		mm	Bobbin Physical Winding Width
M	1				mm	Safety Margin Width
Lg			0.22		mm	Gap Length NON GLASS BEAD Construction
NP			171		Turns	Number of Primary Turns
NS			20		Turns	Number of Secondary Turns
NB			15		Turns	
RB			< 956		OM	
PIV				40	Volts	
N1				34	Turns	Auxiliary Number of Turns
PIV1				67	Volts	Auxiliary Rectifier Maximum Peak Inverse Voltage

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N2				15	Turns	Auxiliary Number of Turns
PIV2				30	Volts	Auxiliary Rectifier Maximum Peak Inverse Voltage
N3				15	Turns	Auxiliary Number of Turns
PIV3				30	Volts	Auxiliary Rectifier Maximum Peak Inverse Voltage
Vc				4.4	Volts	稳压电容上电压
Vz				4.7	Volts	稳压管电压
Rp		>0.092 Wate		3.48	OM	电流检测 (电流限制) 电阻

CURRENT WAVEFORM SHAPE PARAMETERS

Iavgmax	0.02	Amps	Maximum Average Primary Current
Iavgmin	0.01	Amps	Minimum Average Primary Current
IRMS	0.09	Amps	Primary RMS Current
IR	0.27	Amps	Primary Ripple Current
ISP	2.00	Amps	Maximum Peak Secondary Current
ISRMS	0.82	Amps	Secondary RMS current
IRIPPLE	0.65	Amps	Output Capacitor RMS Ripple Current
ISPMAX	2.15	Amps	Maximum Power Peak Secondary Current

TRANSFORMER PARAMETERS

L	4		Number of Primary Layers
BM	2298	Gauss	Operating Flux Density at Max Current Limit
BAC	1140	Gauss	AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)
ur	1654		Relative Permeability of Ungapped Core
BWE	26	mm	Effective Bobbin Width
OD	0.15	mm	Maximum Primary Wire Diameter including insulation
INS	0.03	mm	Taping between primary layers can be eliminated using "Class 0" (Asia), "Grade 2" (Europe) or "Heavy Nyleze" (USA) wire
DIA	0.12	mm	Bare conductor diameter
AWG	37	AWG	Primary Wire Gauge (for low capacitance AWG<= 36 recommended)
CM	20	Cmils	Bare conductor effective area in circular mils
CMA	215	Cmils/Ar	Primary Winding Current Capacity (CMA > 200)
CMS	175	Cmils	Secondary Bare Conductor minimum circular mils
AWGS	27	AWG	Secondary Wire Gauge (Rounded up to next larger standard AWG value)
DIAS	0.36	mm	Secondary Minimum Bare Conductor Diameter
DIA1		mm	第一副绕组线直径
DIA2		mm	第二副绕组线直径
DIA3		mm	第三副绕组线直径
Sc	9.59	mm^2	绕组占窗口静面积

RCC 电路

